## NSN 5961-01-249-1025

Transistor - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-249-1025 **Inclosure Material:** Metal **Overall Length:** 0.265 inches **Terminal Length:** 0.500 inches **Overall Diameter:** 0.205 inches **Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-98 **Mounting Method: Terminal Terminal Circle Diameter:** 0.105 inches **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 70.0 collector to base voltage/static/emitter open and 70.0 collector to emitter voltage, dc with base short-circuited to emitter and 60.0 collector to emitter voltage/static/base open and 5.0 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** 750.00 milliamperes source cutoff current **Power Rating Per Characteristic:** 500.0 milliwatts small-signal input power, common-collector major **Transfer Ratio:** 60.0 static forward current transfer ratio, common-emitter and 120.0 static forward current transfer ratio, common-emitter **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Special Features:** Junction pattern arrangement: pnp **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure:** 

**Fiig:** A110a0

No

**Demilitarization:**